



# RGF10AH THRU RGF10MH

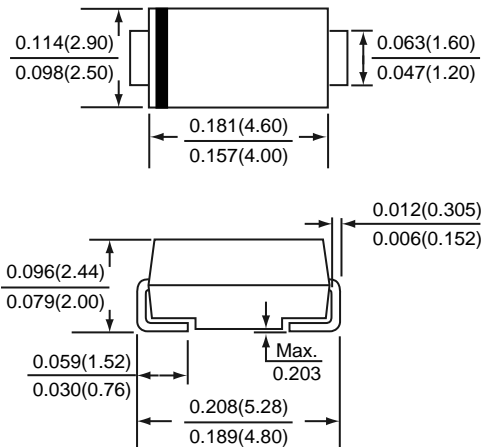
## SURFACE MOUNT GLASS PASSIVATED JUNCTION FAST RECOVERY RECTIFIER

Reverse Voltage - 50 to 1000 Volts

Forward Current - 1.0 Ampere

**PATENTED**

SMA/DO-214AC



\*Dimensions in inches and (millimeters)

**SUPEREX II**<sup>TM</sup>



### FEATURES

- \* Halogen-free type
- \* Compliance to RoHS product
- \* GPRC (Glass Passivated Rectifier Chip) inside
- \* Glass passivated cavity-free junction
- \* Ideal for surface mount automated applications
- \* Fast switching for high efficiency
- \* Easy pick and place
- \* High temperature soldering guaranteed: 260°C/10 seconds, at terminals
- \* Plastic package has Underwriters Laboratory Flammability Classification 94V-0

### MECHANICAL DATA

**Case :** JEDEC DO-214AC molded plastic over passivated chip

**Terminals :** Tin plated, solderable per MIL-STD-750, Method 2026

**Polarity :** Color band denotes cathode end

**Weight :** 0.002 ounces , 0.064 gram

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.	SYMBOLS	RGF10										UNITS
		AH	BH	DH	GH	JH	JAH	KH	KAH	MH	MAH	
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	600	800	800	1000	1000	Volts
Maximum RMS voltage	VRMS	35	70	140	280	420	420	560	560	700	700	Volts
Maximum DC blocking voltage	VDC	50	100	200	400	600	600	800	800	1000	1000	Volts
Maximum average forward rectified current TL=100°C	I (AV)	1.0										Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	30										Amps
Maximum instantaneous forward voltage at 1.0 A	VF	1.3										Volts
Maximum DC reverse current at rated DC blocking voltage	IR	5 30 50										uA
Maximum reverse recovery time (NOTE 1)	trr	150			250	150	500	300	500	300		nS
Typical junction capacitance (NOTE 2)	CJ	15										pF
Typical thermal resistance (NOTE 3)	R θJA R θJL	75 29										°C / W
Operating junction and storage temperature range	TJ,TSTG	-65 to +175										°C

NOTES : (1) Reverse recovery test condition : IF 0.5A, IR=1.0A, Irr=0.25A

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts

(3) Thermal resistance from junction to ambient and from junction to lead P.C.B. mounted on 0.2 x 0.2" (5.0 x 5.0mm) copper pad areas.

# RATINGS AND CHARACTERISTIC CURVES RGF10AH THRU RGF10MH

FIG.1 - FORWARD CURRENT DERATING CURVE

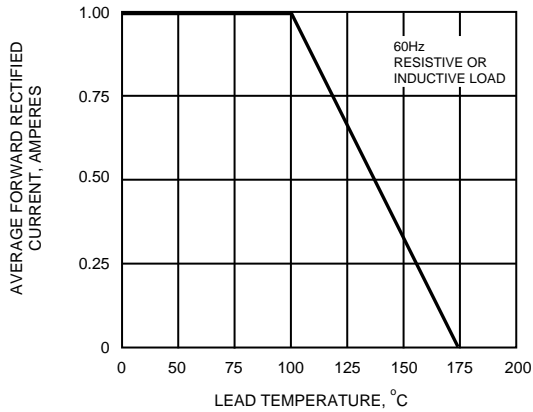


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

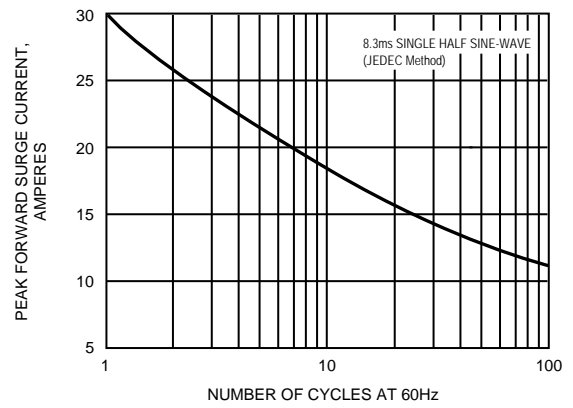


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

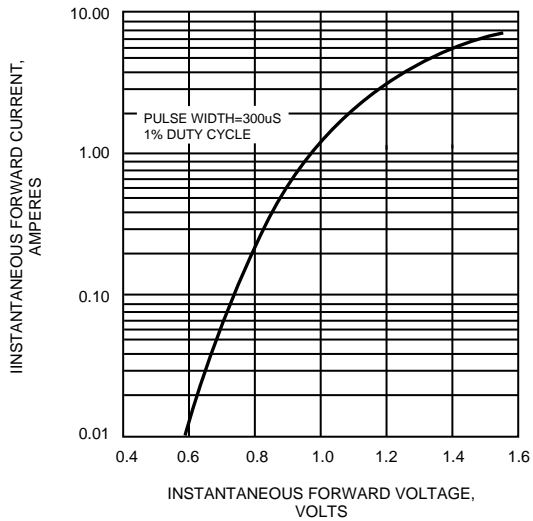


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

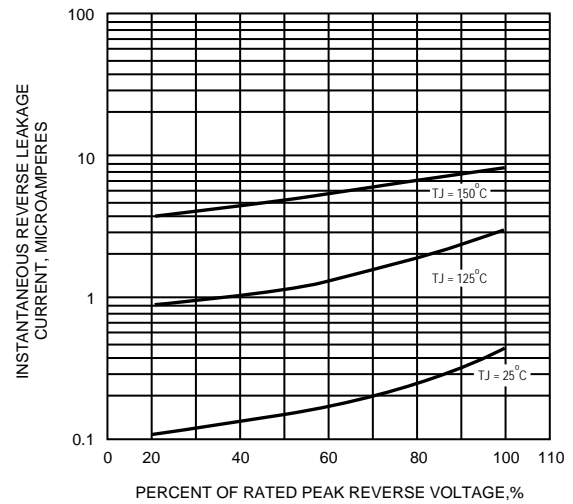


FIG.5 - TYPICAL JUNCTION CAPACITANCE

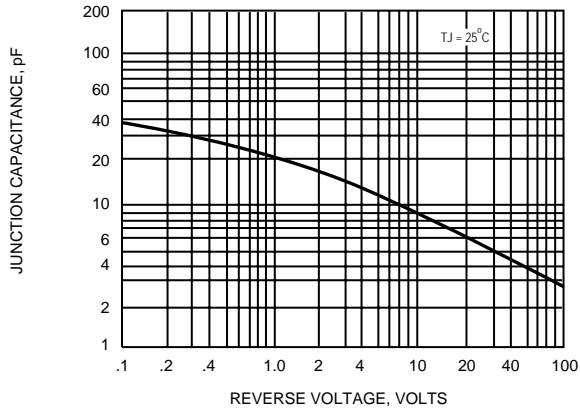


FIG.6 - TYPICAL TRANSIENT THERMAL IMPEDANCE

